Product data sheet

1. General description

Ultrafast power diode in a 2-lead TO247-2L plastic package.

2. Features and benefits

- Fast switching
- Very low on-state loss
- Low leakage current
- Low thermal resistance

3. Applications

- Active PFC in air conditioner
- S.M.P.S Power Factor Correction (PFC)
- · Half-bridge / full-bridge switched-mode power supplies

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Va	lues		Unit	
Absolute maximum rating								
V_{RRM}	repetitive peak reverse voltage			6	00		V	
I _{F(AV)}	average forward current	δ = 0.5 ; square-wave pulse; $T_{mb} \le$ 129 °C; Fig. 1; Fig. 2; Fig. 3	30			А		
I _{FRM}	repetitive peak forward current	δ = 0.5 ; t _p = 25 μs; T _{mb} ≤ 129 °C; square-wave pulse	60			А		
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	290 330			А		
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse				Α		
Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
Static ch	aracteristics							
V _F	forward voltage	I _F = 30 A; T _j = 25 °C; <u>Fig. 6</u>		-	1.18	1.55	V	
		I _F = 30 A; T _j = 150 °C; <u>Fig. 6</u>		-	0.98	-	V	
Dynamic	characteristics							
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}$; $V_R = 30 \text{ V}$; $dI_F/dt = 50 \text{ A}/\mu\text{s}$; $T_j = 25 \text{ °C}$; Fig. 7		-	42	75	ns	
		$I_F = 30 \text{ A}$; $V_R = 400 \text{ V}$; $dI_F/dt = 200 \text{ A/}\mu\text{s}$; $T_j = 25 \text{ °C}$; Fig. 7		-	65	-	ns	
		$I_F = 30 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A/}\mu\text{s};$ $T_j = 125 \text{ °C}; Fig. 7$		-	101	-	ns	

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		и I/I л
2	А	anode		K A 001aaa020
mb	mb	mounting base; connected to cathod	K A TO247-2L	

6. Ordering information

Table 3. Ordering information

Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
BYV30W-600PT2	TO247-2L	BYV30W-600PT2Q	Tube	30	TO247L-2L	10-Nov-2020

7. Marking

Table 4. Marking codes

Type number	Marking codes
BYV30W-600PT2	BYV30W 600PT2

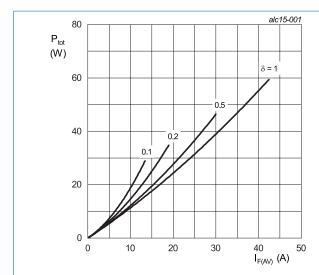
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8. Limiting values

Table 5. Limiting values

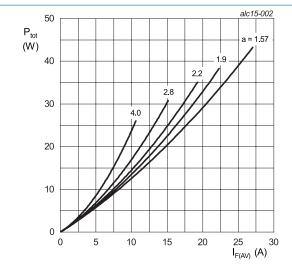
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V_{RRM}	repetitive peak reverse voltage		600	V
V_{RWM}	crest working reverse voltage		600	V
V_R	reverse voltage	DC	600	V
I _{F(AV)}	average forward current	$δ$ = 0.5; square-wave pulse; $T_{mb} \le 129$ °C; Fig. 1; Fig. 2; Fig. 3	30	Α
I _{FRM}	repetitive peak forward current	$δ = 0.5$; $t_p = 25 \mu s$; $T_{mb} \le 129 °C$; square-wave pulse	60	А
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	290	А
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	330	Α
T _{stg}	storage temperature		-55 to 175	°C
T _j	junction temperature		175	°C



$$\begin{split} I_{\text{F(AV)}} &= I_{\text{F(RMS)}} \times \sqrt{\delta} \\ V_{\text{o}} &= 1.051 \text{ V; R}_{\text{s}} = 0.0083 \text{ } \Omega \end{split}$$

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



a = form factor = $I_{F(RMS)}/I_{F(AV)}$ V_o = 1.051 V; R_s = 0.0083 Ω

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

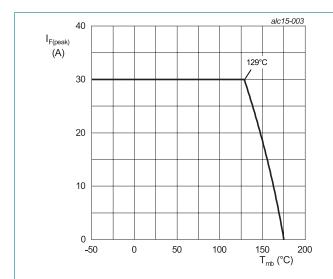


Fig. 3. Forward current as a function of mounting base temperature; maximum values

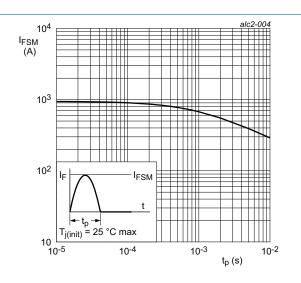


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. 5	-	-	1	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air	-	45	-	K/W

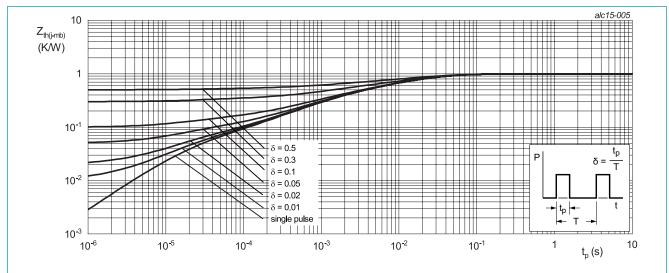
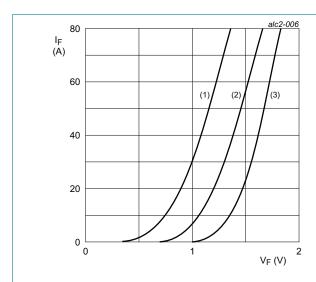


Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
	aracteristics			J 31		
V_{F}	forward current	I _F = 30 A; T _j = 25 °C; <u>Fig. 6</u>	-	1.18	1.55	V
		I _F = 30 A; T _j = 150 °C; <u>Fig. 6</u>	-	0.98	-	V
I _R	reverse current	V _R = 600 V; T _j = 25 °C	-	2	10	μA
		V _R = 600 V; T _j = 125 °C	-	-	500	μA
Dynamic	characteristics					
Q _r	reverse charge	$I_F = 30 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$	-	272	-	nC
		$I_F = 30 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A/}\mu\text{s};$ $T_j = 125 \text{ °C}; Fig. 7$	-	775	-	nC
t _{rr} reverse recovery	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 50 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$	-	42	75	ns
		$I_F = 30 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$	-	65	-	ns
		$I_F = 30 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A/}\mu\text{s};$ $T_i = 125 \text{ °C}; Fig. 7$	-	101	-	ns
I _{RM}	peak reverse recovery current	$I_F = 30 \text{ A}$; $V_R = 400 \text{ V}$; $dI_F/dt = 200 \text{ A/}\mu\text{s}$; $T_J = 25 ^{\circ}\text{C}$; $Fig. 7$	-	8.4	-	А
		$I_F = 30 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A/}\mu\text{s};$ $T_i = 125 \text{ °C}; Fig. 7$	-	15.2	-	А



 V_{o} = 1.051 V; R_{s} = 0.0083 Ω

(1) $T_j = 150$ °C; typical values (2) $T_j = 150$ °C; maximum values (3) $T_j = 25$ °C; maximum values

Fig. 6. Forward current as a function of forward voltage

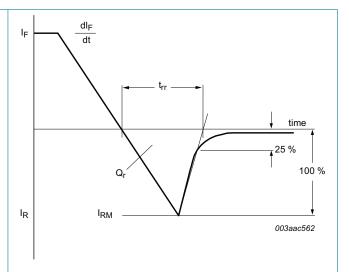
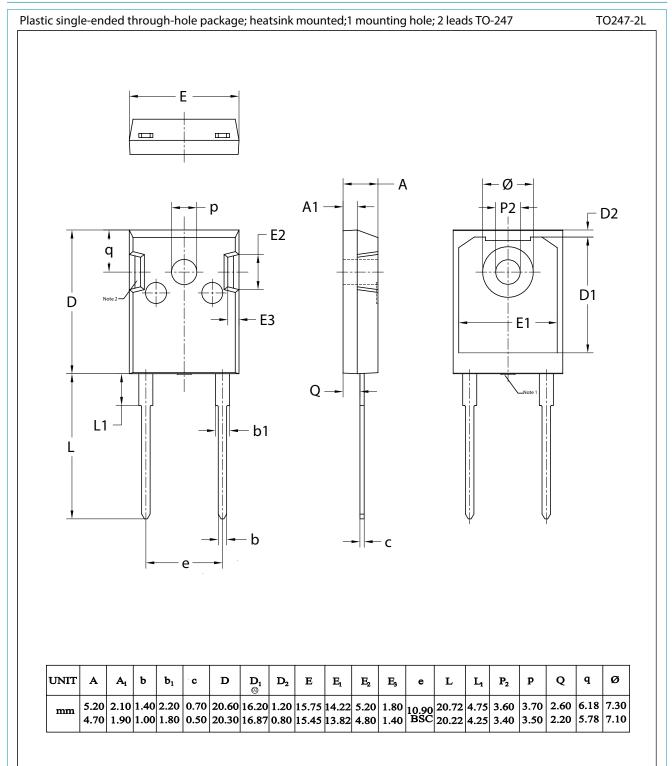


Fig. 7. Reverse recovery definitions; ramp recovery

11. Package outline



Note:

- 1. Mold resin protrusion max 0.127mm.
- Metal exposed with Sn plating.

BYV30W-600PT2

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Date of release: 12 November 2020

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